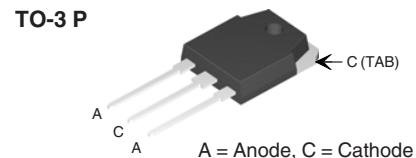
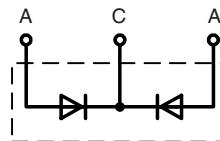


## FRED for PDP Applications with common cathode and soft recovery

$I_{FAV} = 2 \times 30 \text{ A}$   
 $V_{RRM} = 200 \text{ V}$   
 $t_{rr} = 25 \text{ ns}$

$V_{RSM}$ V	$V_{RRM}$ V	Type
200	200	DSEC 60-02AQ



Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$		70	A
$I_{FAVM}$	$T_c = 145^\circ\text{C}$ ; rectangular, $d = 0.5$	30	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine	325	A
$E_{AS}$	$T_{VJ} = 25^\circ\text{C}$ ; non-repetitive $I_{AS} = 3 \text{ A}$ ; $L = 180 \mu\text{H}$	1.2	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_R$ typ.; $f = 10 \text{ kHz}$ ; repetitive	0.3	A
$T_{VJ}$		-55...+175	°C
$T_{VJM}$		175	°C
$T_{stg}$		-55...+150	°C
$P_{tot}$	$T_c = 25^\circ\text{C}$	165	W
$M_d$	mounting torque	0.8...1.2	Nm
$F_c$	mounting force with clip	20...120	N
Weight	typical	5.2	g

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$ ①	$V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ ; $T_{VJ} = 150^\circ\text{C}$	3 200	$\mu\text{A}$ $\mu\text{A}$
$V_F$ ②	$I_F = 30 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$	0.95 1.20	V V
$R_{thJC}$ $R_{thCH}$		0.25	K/W K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-\text{di}/\text{dt} = 200 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	25	ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 50 \text{ A}$ ; $-\text{di}_F/\text{dt} = 100 \text{ A}/\mu\text{s}$ ; $T_{VJ} = 100^\circ\text{C}$	4	A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
 ② Pulse Width = 300  $\mu\text{s}$ , Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

### Features

- International standard package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

### Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{RM}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commuting switch

**Recommended replacement:**  
**DPG 60C200QB**

IXYS reserves the right to change limits, test conditions and dimensions.

© 2007 IXYS All rights reserved

20070605b

1 - 2

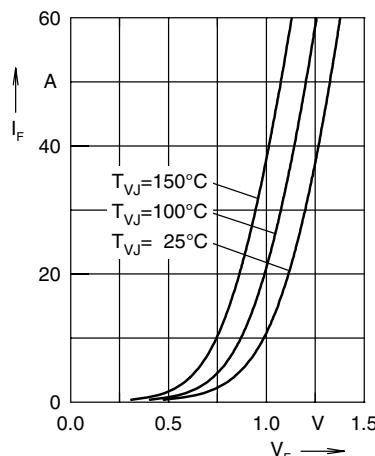
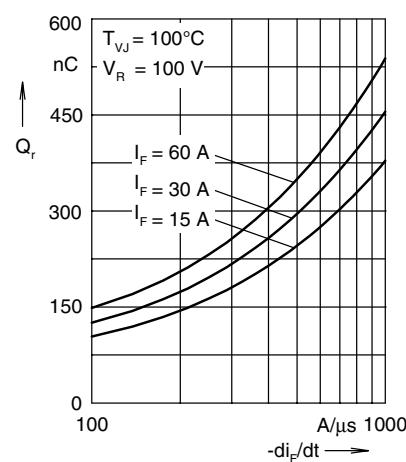
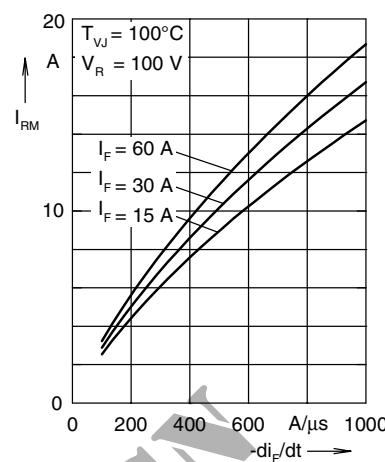
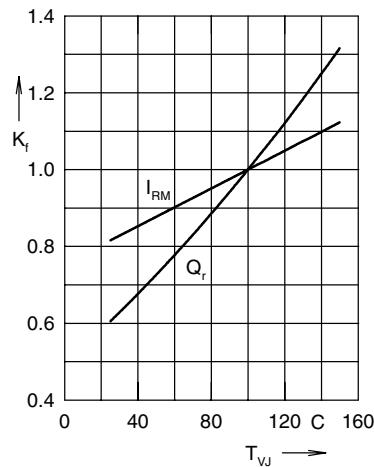
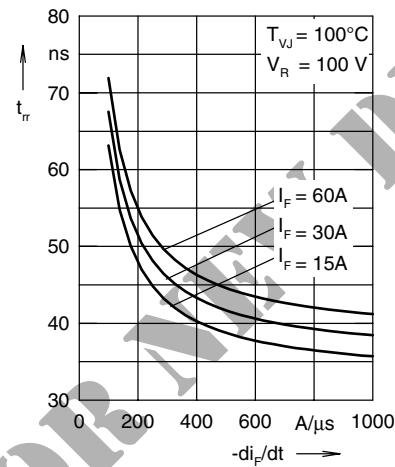
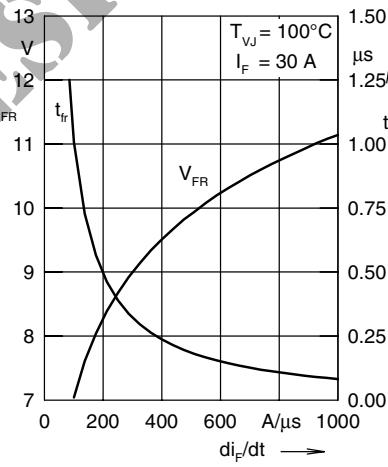
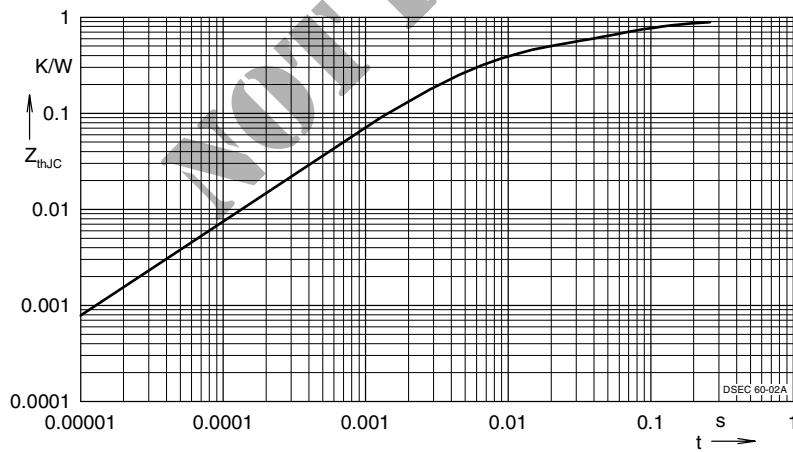
Fig. 1 Forward current  $I_F$  vs.  $V_F$ Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$ Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$ Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$ Fig. 5 Recovery time  $t_{rr}$  vs.  $-di_F/dt$ Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$ 

Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.465	0.005
2	0.179	0.0003
3	0.256	0.04

NOTE: Fig. 2 to Fig. 6 shows typical values